

# 2SD2242, 2SD2242A

## Silicon NPN triple diffusion planar type Darlington

For power amplification

### ■ Features

- High forward current transfer ratio  $h_{FE}$
- High-speed switching
- Allowing supply with the radial taping

### ■ Absolute Maximum Ratings $T_C = 25^\circ\text{C}$

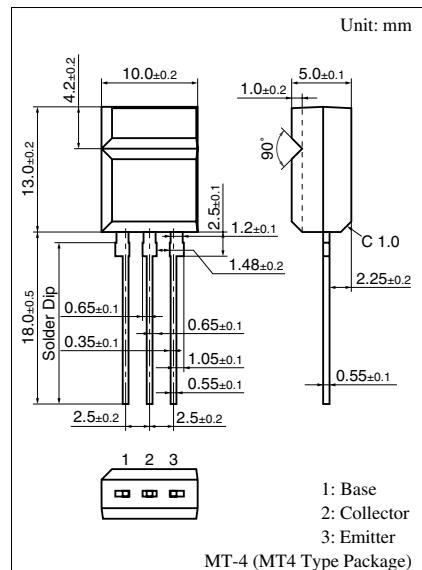
Parameter	Symbol	Rating	Unit
Collector to base voltage	$V_{CBO}$	60	V
2SD2242A	80		
Collector to emitter voltage	$V_{CEO}$	60	V
2SD2242A	80		
Emitter to base voltage	$V_{EBO}$	5	V
Peak collector current	$I_{CP}$	8	A
Collector current	$I_C$	4	A
Collector power dissipation	$P_C$	15	W
$T_a = 25^\circ\text{C}$		2	
Junction temperature	$T_j$	150	$^\circ\text{C}$
Storage temperature	$T_{stg}$	-55 to +150	$^\circ\text{C}$

### ■ Electrical Characteristics $T_C = 25^\circ\text{C}$

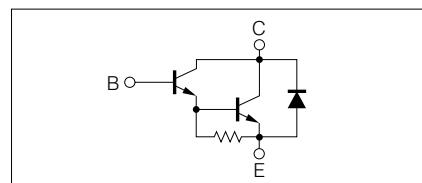
Parameter	Symbol	Conditions	Min	Typ	Max	Unit	
Collector cutoff current	$I_{CBO}$	$V_{CB} = 60 \text{ V}, I_E = 0$			200	$\mu\text{A}$	
2SD2242A		$V_{CB} = 80 \text{ V}, I_E = 0$			200		
Collector cutoff current	$I_{CEO}$	$V_{CE} = 30 \text{ V}, I_B = 0$			500	$\mu\text{A}$	
2SD2242A		$V_{CE} = 40 \text{ V}, I_B = 0$			500		
Emitter cutoff current	$I_{EBO}$	$V_{EB} = 5 \text{ V}, I_C = 0$			2	$\mu\text{A}$	
Collector to emitter voltage	$V_{CEO}$	$I_C = 30 \text{ mA}, I_B = 0$	60			V	
2SD2242A			80				
Forward current transfer ratio		$h_{FE1}$	1 000				
		$h_{FE2}^*$	2 000		10 000		
Base to emitter voltage		$V_{BE}$	$V_{CE} = 3 \text{ V}, I_C = 3 \text{ A}$		2.5	V	
Collector to emitter saturation voltage		$V_{CE(\text{sat})}$	$I_C = 3 \text{ A}, I_B = 12 \text{ mA}$		2	V	
			$I_C = 5 \text{ A}, I_B = 20 \text{ mA}$		4		
Transition frequency	$f_T$	$V_{CE} = 10 \text{ V}, I_C = 0.5 \text{ A}, f = 1 \text{ MHz}$		20		MHz	
Turn-on time	$t_{on}$	$I_C = 3 \text{ A}, I_{B1} = 12 \text{ mA}, I_{B2} = -12 \text{ mA}, V_{CC} = 50 \text{ V}$		0.5		$\mu\text{s}$	
Storage time	$t_{stg}$			4		$\mu\text{s}$	
Fall time	$t_f$			1		$\mu\text{s}$	

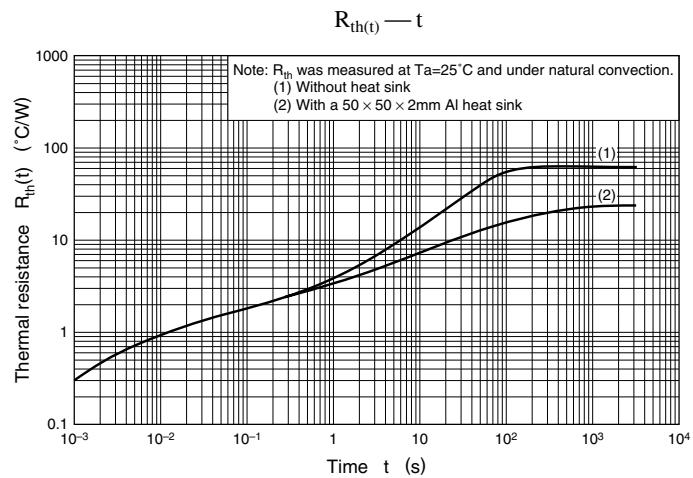
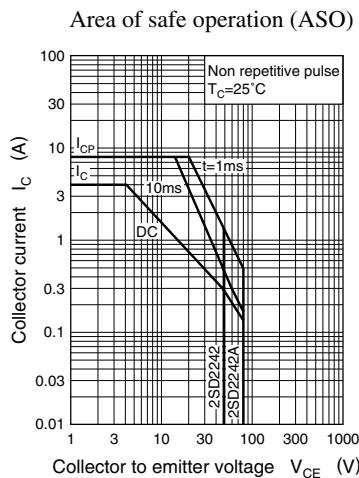
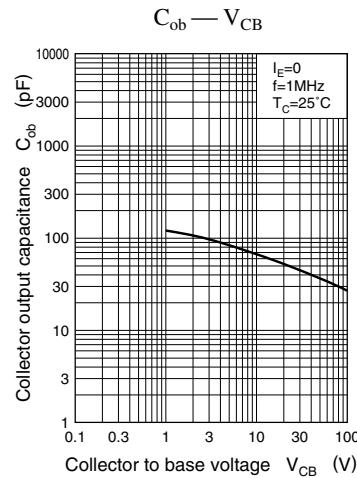
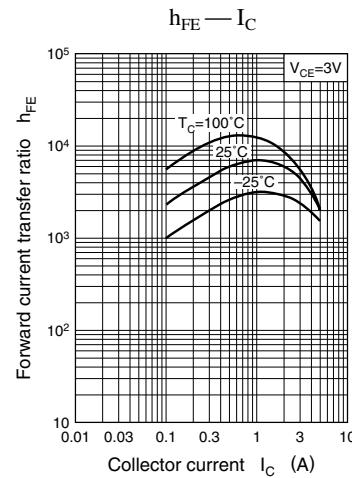
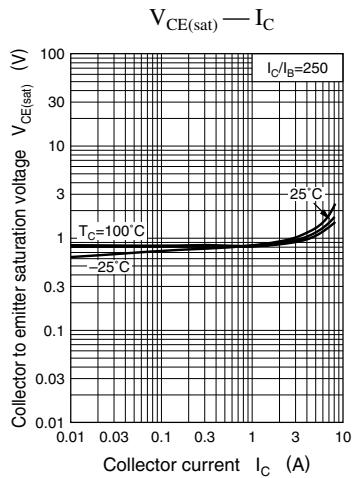
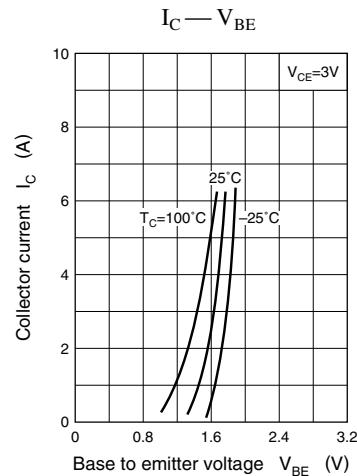
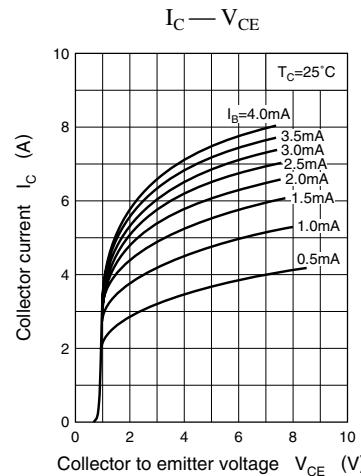
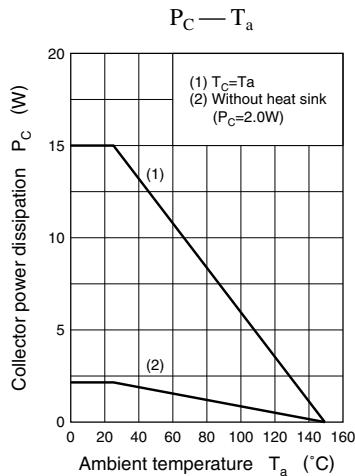
Note) \*: Rank classification

Rank	Q	R
$h_{FE2}$	2 000 to 5 000	4 000 to 10 000



### Internal Connection





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